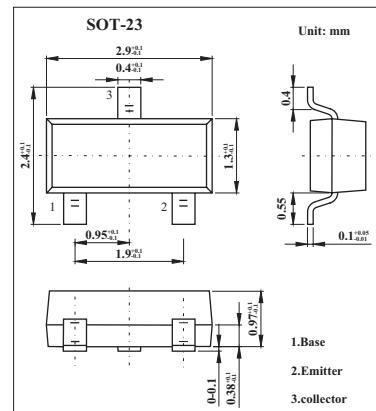
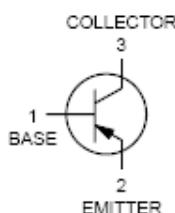


General Purpose Amplifier

MMBTA20

■ Features

- General Purpose Amplifier.



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-emitter voltage	VCEO	40	V
Emitter-base voltage	VEBO	4	V
Collector current	Ic	100	mA
Total Device Dissipation FR-5 Board (* 1) @Ta = 25°C Derate above 25°C	Pd	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	RθJA	556	°C/W
Total Device Dissipation Alumina Substrate, (* 2) @Ta = 25°C Derate above 25°C	Pd	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	RθJA	417	°C/W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

* 1. FR-5 = 1.0 X 0.75 X 0.062 in.

* 2. Alumina = 0.4 X 0.3 X 0.024 in. 99.5% alumina.

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector-emitter breakdown voltage	V(BR)CEO	Ic = 1.0 mA, Ib = 0	40			V
Emitter-base breakdown voltage	V(BR)EBO	Ie = 10 μA, Ic = 0	4.0			V
Collector cutoff current	Icbo	Vcb = 30 V, Ie = 0			100	nA
DC current gain	HFE	Ic = 5.0 mA, Vce = 10 V	40		400	
Collector-emitter saturation voltage	Vce(sat)	Ic = 10 mA, Ib = 1.0 mA			0.25	V
Current-gain-bandwidth product	ft	Ic = 5.0 mA, Vce = 10 V, f = 100 MHz	125			MHz
Output capacitance	Cobo	Vcb = 5.0 V, Ie = 0, f = 1.0 MHz			4.0	pF

■ Marking

Marking	1C
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